10/751,439

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	10/751439	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:10
L2	1	("6204524").PN.	USPAT	OR	OFF	2005/12/02 17:11
L3	1	("6310366").PN.	USPAT	OR	OFF	2005/12/02 17:11
L4	1	("6326652").PN.	USPAT	OR	OFF	2005/12/02 17:15
L5	1	"6069376".PN.	USPAT; USOCR	OR	ON	2005/12/02 17:12
L6	1	"5929489".PN.	USPAT; USOCR	OR	ON	2005/12/02 17:12
L7	1	"5461425".PN.	USPAT; USOCR	OR	ON	2005/12/02 17:12
L8	0	pixel and cell and photosensitive and device and image and transistor and hallo and source and drain and LDD and implant$ and enhancement	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:19
L9	0	pixel and cell and photosensitive and device and image and transistor and hallo and source and drain and LDD and implant$	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:18
L10	0	pixel and cell and device and image and transistor and hallo and source and drain and LDD and implant$	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:18
L11	1	pixel and cell and photosensitive and device and image and transistor and halo and source and drain and LDD and implant$ and enhancement	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:19
L12	2	pixel and cell and device and image and transistor and halo and source and drain and LDD and implant$ and enhancement	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:20

L13	1	pixel and cell and device and image and transistor and (no adj halo) and source and drain and LDD and implant$ and (no adj enhancement) and lightly and doped	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:22
L14	27	pixel and cell and device and image and transistor and source and drain and LDD and implant$ and lightly and doped and CMOS and CCD and gate and spacer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:36
L15	3	pixel and cell and device and image and transistor and source and drain and LDD and implant$ and lightly and doped and CMOS and CCD and gate and spacer and halo	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:29
L16	1331	438/48	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:36
L17	337	438/60	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:36
L18	2546	438/197	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:36
L19	1306	438/287	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:36
L20	1019	438/289	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37

L21	422	438/311		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37
L22	3509	438/257		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37
L23	947	438/286		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37
L24	1449	438/680		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37
L25	678	438/681		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37
L26	1080	438/682		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37
L27	173	438/679		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37
L28	279	438/684		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37

L29	4178	438/692		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:37
L30	713	438/297		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:38
L31	1224	438/685		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:38
L32	582	438/686		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:38
L33	1157	438/683		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:38
L34	42	438/953		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 17:38